



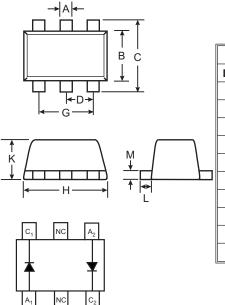
DUAL SURFACE MOUNT SCHOTTKY BARRIER DIODE

Features

- Low Forward Voltage Drop
- Fast Switching
- PN Junction Guard Ring for Transient and **ESD** Protection
- Lead Free By Design/RoHS Compliant (Note 1)
- "Green" Device (Note 4)

Mechanical Data

- Case: SOT-563
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture sensitivity: Level 1 per J-STD-020C
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin annealed over Alloy 42 leadframe. Solderable per MIL-STD-202, Method 208
- Marking & Type Code Information: See Last Page
- Ordering Information: See Last Page
- Weight: 0.003 grams (approx.)



SOT-563										
Dim	Min Max Typ									
Α	0.15	0.30	0.25							
В	1.10	1.10 1.25 1.20								
С	1.55 1.70 1.60									
D	0.50									
G	0.90	1.00								
н	1.50 1.70 1.60									
К	0.56 0.60 0.60									
L	0.10	0.30	0.20							
М	0.10	0.18	0.11							
All Dimensions in mm										

Maximum Ratings @ T_A = 25°C unless otherwise specified

Characteristic		Symbol	Value	Unit	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		V _{RRM} V _{RWM} V _R	40	V	
Forward Continuous Current (Note 2)	I _{FM}	200	mA		
Forward Surge Current (Note 2) @ t < 1.0s		I _{FSM}	600	mA	
Operating Temperature Range		Tj	-55 to +125	°C	
Storage Temperature Range	T _{STG}	-65 to +150	°C		

Thermal Characteristics @ $T_A = 25^{\circ}C$ unless otherwise specified

Characteristic	Symbol	Value	Unit	
Power Dissipation (Note 2)	Pd	150	mW	
Thermal Resistance, Junction to Ambient Air (Note 2)	$R_{ ext{ heta}JA}$	833	°C/W	

Electrical Characteristics @ T_A = 25°C unless otherwise specified

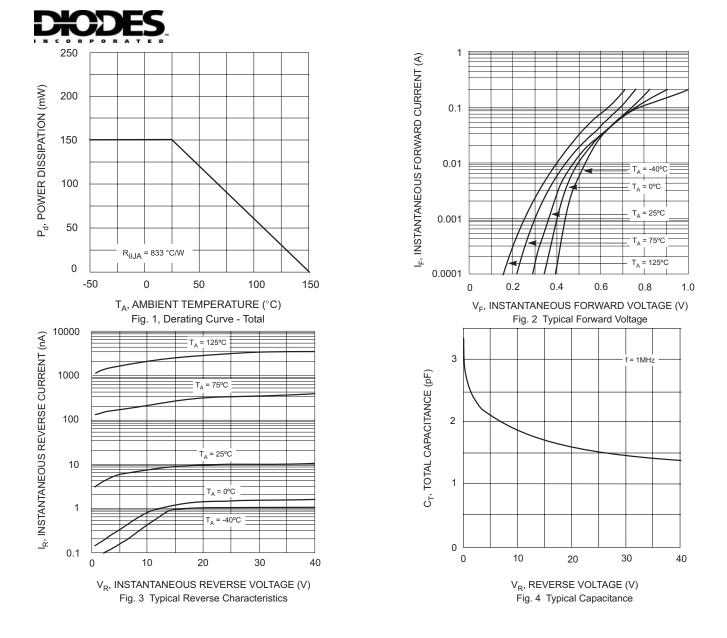
Characteristic		Min	Тур	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 3)	V _{(BR)R}	40	—	—	V	$I_{R} = 10 \mu A$
Forward Voltage	VF	—	—	380 1000	mV	$t_p < 300 \mu s, I_F = 1.0 mA$ $t_p < 300 \mu s, I_F = 40 mA$
Reverse Leakage Current (Note 3)	I _R	_	20	200	nA	$t_p < 300 \mu s, V_R = 30 V$
Total Capacitance	Ст	_	4.0	5.0	pF	$V_{R} = 0V, f = 1.0MHz$
Reverse Recovery Time	t _{rr}	_		5.0	ns	$ I_F = I_R = 10 mA \text{ to } I_R = 1.0 mA, \\ R_L = 100 \Omega $

Note: 1. No purposefully added lead.

2. Part mounted on FR-4 board with recommended pad layout, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

3. Short duration test pulse used to minimize self-heating effect.

4. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.

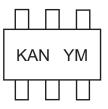


Ordering Information (Note 4)

Device	Packaging	Shipping
BAS40V-7	SOT-563	3000/Tape & Reel

Notes: 4. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



 $\begin{array}{l} \mathsf{KAN} = \mathsf{Product} \ \mathsf{Type} \ \mathsf{Marking} \ \mathsf{Code} \\ \mathsf{YM} = \mathsf{Date} \ \mathsf{Code} \ \mathsf{Marking} \\ \mathsf{Y} = \mathsf{Year} \ (\mathsf{ex:} \ \mathsf{R} = 2004) \\ \mathsf{M} = \mathsf{Month} \ \mathsf{ex:} \ 9 = \mathsf{September} \end{array}$

Date Code Key

Year		2004		2005	2006	2	007	2008	2009	20	10	2011	2012
Code		R		S	Т		U	V	W)		Y	Z
Month	Jan	Feb	March	Ар	or Ma	ay	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	5	6	7	8	9	0	N	D



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